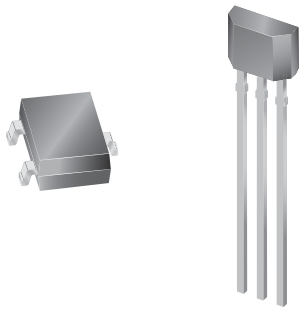
Continuous-Time Bipolar Switch Family

Features and Benefits

- Continuous-time operation
  - Fast power-on time
  - Low noise
- Stable operation over full operating temperature range
- Reverse battery protection
- Solid-state reliability
- Factory-programmed at end-of-line for optimum performance
- Robust EMC performance
- High ESD rating
- Regulator stability without a bypass capacitor

Packages: 3 pin SOT23W (suffix LH), and 3 pin SIP (suffix UA)



Not to scale

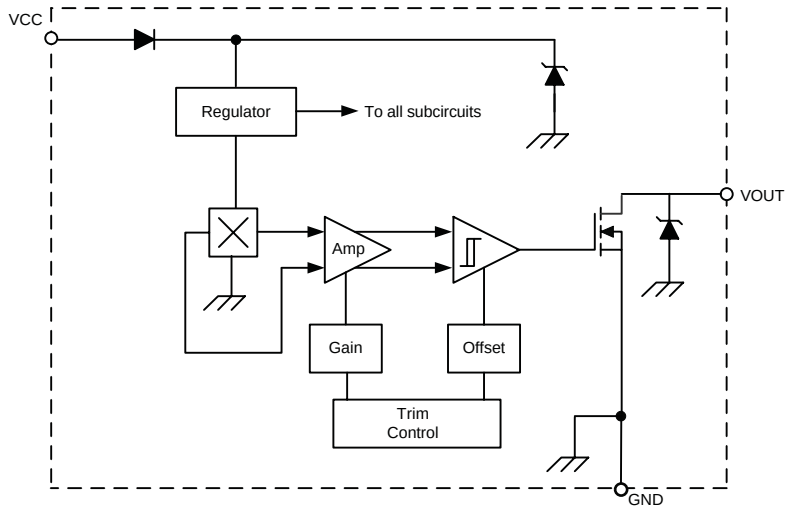
Description

The Allegro® A1201, A1202, A1203, and A1204 Hall-effect bipolar switches are next-generation replacements and extension of the popular Allegro A3134, A3133, and A3132 bipolar switch product line. Overall, the A120x family, produced with BiCMOS technology, consists of continuous-time devices that feature fast power-on time and low-noise operation. Device programming is performed after packaging, to ensure increased switchpoint accuracy by eliminating offsets that can be induced by package stress. Unique Hall element geometries and low-offset amplifiers help to minimize noise and to reduce the residual offset voltage normally caused by device overmolding, temperature excursions, and thermal stress.

The A120x Hall-effect bipolar switches include the following on a single silicon chip: voltage regulator, Hall-voltage generator, small-signal amplifier, Schmitt trigger, and NMOS output transistor. The integrated voltage regulator permits operation from 3.8 to 24 V. The extensive on-board protection circuitry makes possible a ±30 V absolute maximum voltage rating for superior protection in automotive and motor commutation

Continued on the next page…

Functional Block Diagram



Description (continued)

applications, without adding external components. All devices in the family are identical, except for magnetic switchpoints.

The small geometries of the BiCMOS process allow these devices to be provided in ultrasmall packages. The package styles available provide magnetically optimized solutions for most applications. Package LH is a SOT23W, a miniature low-profile surface-mount package, while package UA is a three-lead ultramini SIP for through-hole mounting. Each package is lead (Pb) free, with 100% matte tin plated leadframes.

Selection Guide[1]

Part Number	Packing[2]	Mounting	Ambient, T_A	B_{RP} (Min)	B_{OP} (Max)
A1201ELHLT-T	7-in. reel, 3000 pieces/reel	3-pin SOT23W surface mount	–40ºC to 85ºC	–50	50
A1201EUA-T	Bulk, 500 pieces/bag	3-pin SIP through hole			
A1201LLHLT-T	7-in. reel, 3000 pieces/reel	3-pin SOT23W surface mount	–40ºC to 150ºC		
A1201LUA-T	Bulk, 500 pieces/bag	3-pin SIP through hole			
A1202ELHLT-T	7-in. reel, 3000 pieces/reel	3-pin SOT23W surface mount	–40ºC to 85ºC	–75	75
A1202EUA-T	Bulk, 500 pieces/bag	3-pin SIP through hole			
A1202LLHLT-T	7-in. reel, 3000 pieces/reel	3-pin SOT23W surface mount	–40ºC to 150ºC		
A1202LUA-T	Bulk, 500 pieces/bag	3-pin SIP through hole			
A1203ELHLT-T	7-in. reel, 3000 pieces/reel	3-pin SOT23W surface mount	–40ºC to 85ºC	–95	95
A1203EUA-T	Bulk, 500 pieces/bag	3-pin SIP through hole			
A1203LLHLT-T	7-in. reel, 3000 pieces/reel	3-pin SOT23W surface mount	–40ºC to 150ºC		
A1203LUA-T	Bulk, 500 pieces/bag	3-pin SIP through hole			

[1] The variants cited in this footnote are in production but have been determined to be NOT FOR NEW DESIGN. This classification indicates that sale of this device is currently restricted to existing customer applications. The variants should not be purchased for new design applications because obsolescence in the near future is probable. Samples are no longer available. Status change: October 31, 2006. These variants include: A1204ELHLT-T, A1204EUA-T, A1204LLHLT-T, and A1204LUA-T.

[2]Contact Allegro for additional packing options.

Absolute Maximum Ratings

Characteristic	Symbol	Notes	Rating	Units
Supply Voltage	V_{CC}		30	V
Reverse Supply Voltage	V_{RCC}		–30	V
Output Off Voltage	V_{OUT}		30	V
Reverse Output Voltage	V_{ROUT}		–0.5	V
Output Current Sink	$I_{OUTSINK}$		25	mA
Magnetic Flux Density	B		Unlimited	G
Operating Ambient Temperature	T_A	Range E	–40 to 85	ºC
		Range L	–40 to 150	ºC
Maximum Junction Temperature	T_J(max)		165	ºC
Storage Temperature	T_{stg}		–65 to 170	ºC

OPERATING CHARACTERISTICS over full operating voltage and ambient temperature ranges, unless otherwise noted

Characteristic	Symbol	Test Conditions		Min.	Typ.	Max.	Units
Electrical Characteristics							
Supply Voltage[1]	V_{CC}	Operating, T_J < 165°C		3.8	–	24	V
Output Leakage Current	I_{OUTOFF}	V_{OUT} = 24 V, B < B_{RP}		–	–	10	µA
Output On Voltage	$V_{OUT(SAT)}$	I_{OUT} = 20 mA, B > B_{OP}		–	215	400	mV
Power-On Time[2]	t_{PO}	Slew rate (dV_{CC}/dt) < 2.5 V/µs, B > B_{OP}(max) + 5 G or B < B_{RP}(min) – 5 G		–	–	4	µs
Output Rise Time[3]	t_r	V_{CC} = 12 V, R_{LOAD} = 820 Ω, C_S = 12 pF		–	–	2	µs
Output Fall Time[3]	t_f	V_{CC} = 12 V, R_{LOAD} = 820 Ω, C_S = 12 pF		–	–	2	µs
Supply Current	I_{CCON}	B > B_{OP}		–	3.8	7.5	mA
	I_{CCOFF}	B < B_{RP}		–	3.5	7.5	mA
Reverse Battery Current	I_{RCC}	V_{RCC} = –30 V		–	–	–10	mA
Supply Zener Clamp Voltage	V_Z	I_{CC} = 30 mA; T_A = 25°C		32	–	–	V
Supply Zener Current[4]	I_Z	V_Z = 32 V; T_A = 25°C		–	–	30	mA
Magnetic Characteristics[5]							
Operate Point	B_{OP}	A1201	South pole adjacent to branded face of device	–40	15	50	G
		A1202		–	26	75	G
		A1203		–	26	95	G
		A1204		–100	42	150	G
Release Point	B_{RP}	A1201	North pole adjacent to branded face of device	–50	–15	40	G
		A1202		–75	–26	–	G
		A1203		–95	–26	–	G
		A1204		–150	–40	100	G
Hysteresis	B_{HYS}	A1201	B_{OP} – B_{RP}	5	30	55	G
		A1202		30	52	–	G
		A1203		30	52	–	G
		A1204		50	82	115	G

[1] Maximum voltage must be adjusted for power dissipation and junction temperature, see *Power Derating* section.
[2] For V_{CC} slew rates greater than 250 V/µs, and T_A = 150°C, the Power-On Time can reach its maximum value.
[3] C_S =oscilloscope probe capacitance.
[4] Maximum current limit is equal to the maximum $I_{CC(max)}$ + 22 mA.
[5] Magnetic flux density, B, is indicated as a negative value for north-polarity magnetic fields, and as a positive value for south-polarity magnetic fields. This so-called algebraic convention supports arithmetic comparison of north and south polarity values, where the relative strength of the field is indicated by the absolute value of B, and the sign indicates the polarity of the field (for example, a –100 G field and a 100 G field have equivalent strength, but opposite polarity).

DEVICE QUALIFICATION PROGRAM

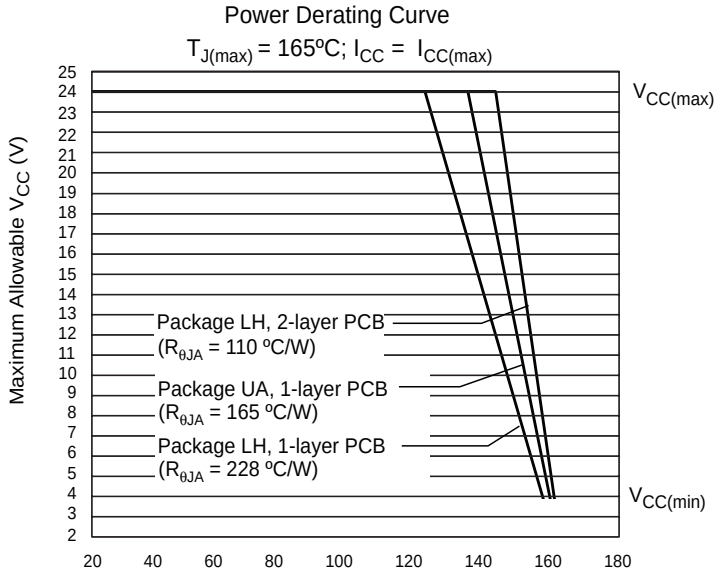
Contact Allegro for information.

EMC (Electromagnetic Compatibility) REQUIREMENTS

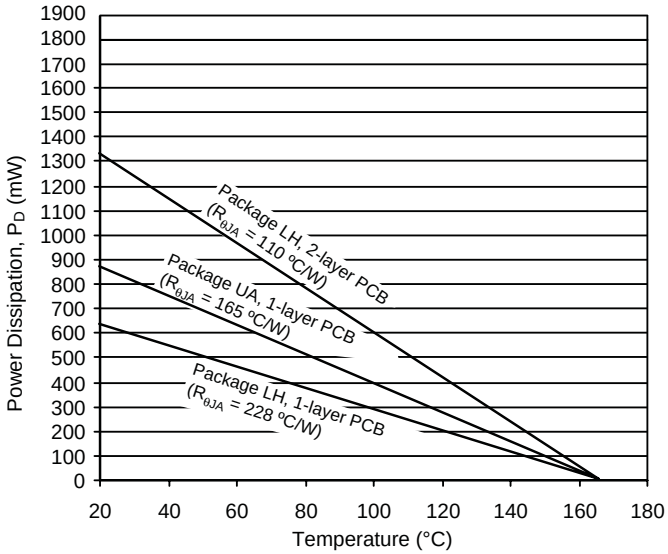
Contact Allegro for information.

THERMAL CHARACTERISTICS may require derating at maximum conditions, see application information

Characteristic	Symbol	Test Conditions	Value	Units
Package Thermal Resistance	$R_{\theta JA}$	Package LH, 1-layer PCB with copper limited to solder pads	228	ºC/W
		Package LH, 2-layer PCB with 0.463 in.^{2} of copper area each side connected by thermal vias	110	ºC/W
		Package UA, 1-layer PCB with copper limited to solder pads	165	ºC/W

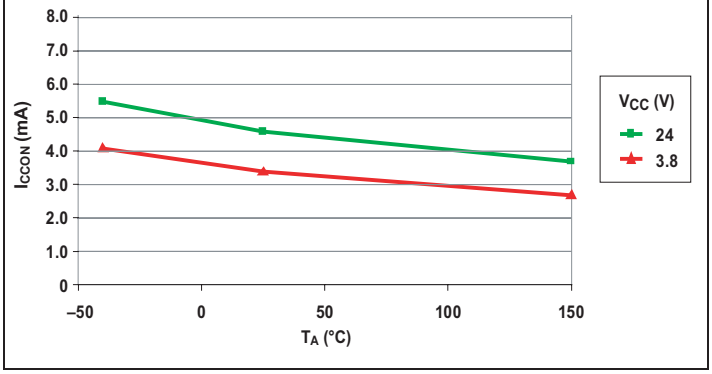


Power Dissipation versus Ambient Temperature

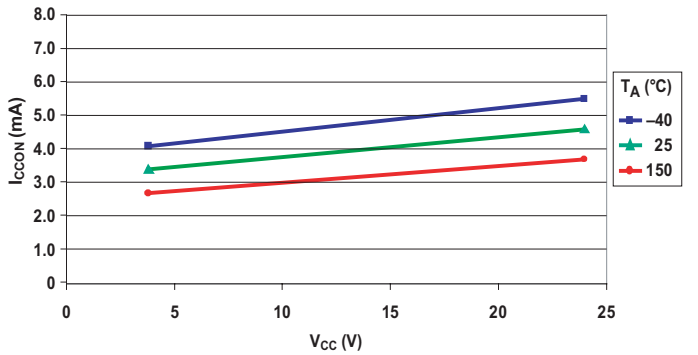


Characteristic Data

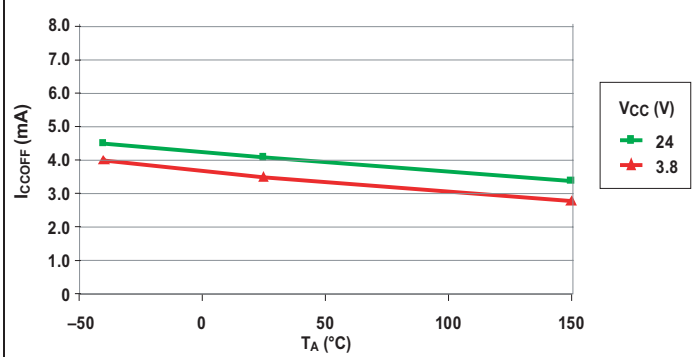
Supply Current (On) versus Ambient Temperature
(A1201/02/03/04)



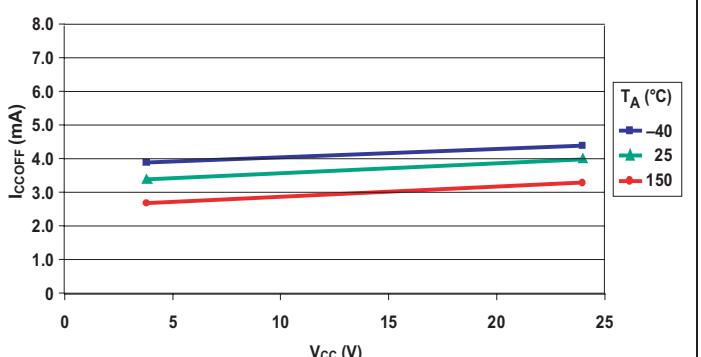
Supply Current (On) versus Supply Voltage
(A1201/02/03/04)



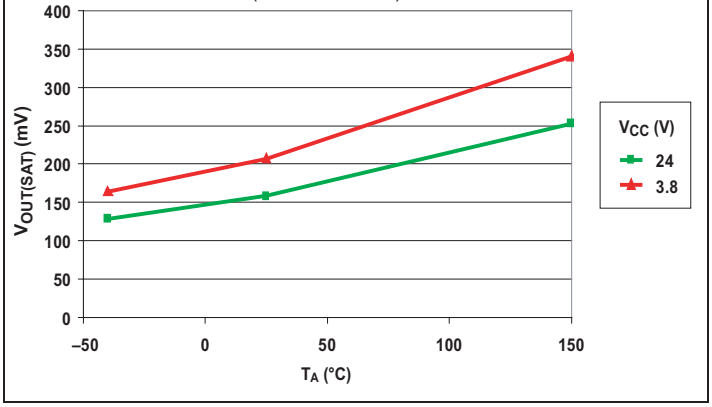
Supply Current (Off) versus Ambient Temperature
(A1201/02/03/04)



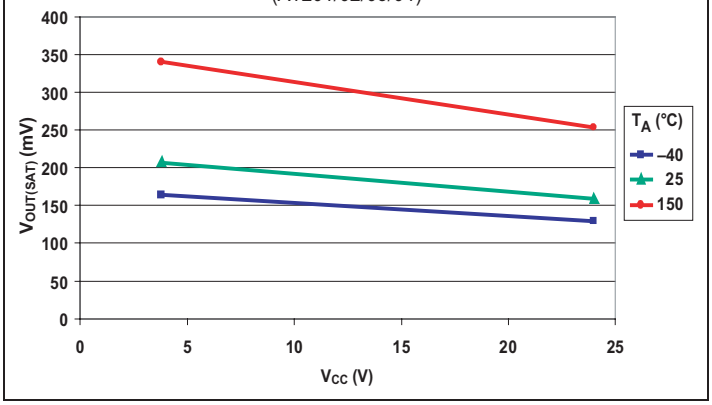
Supply Current (Off) versus Supply Voltage
(A1201/02/03/04)

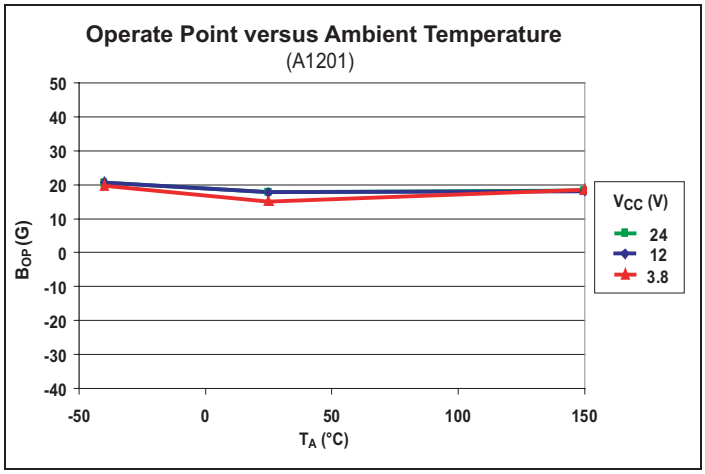


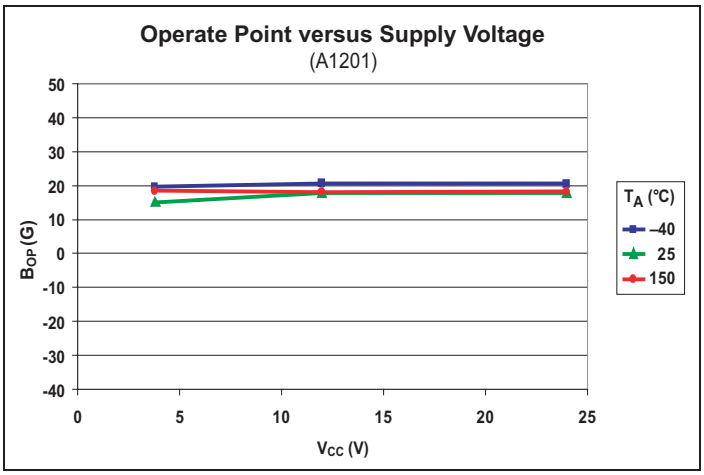
Output Voltage (On) versus Ambient Temperature
(A1201/02/03/04)

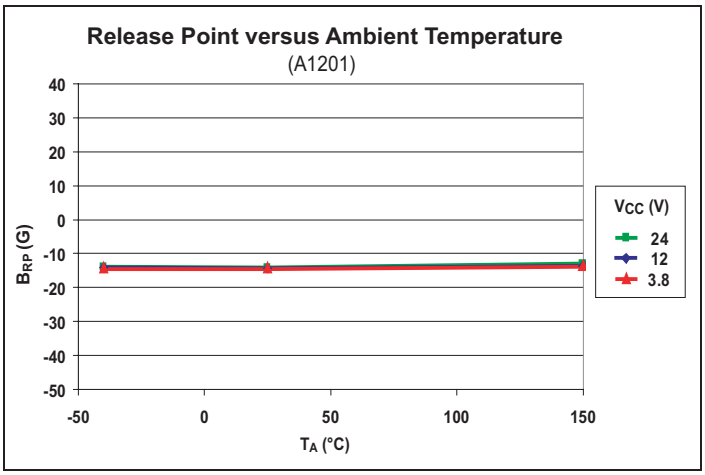


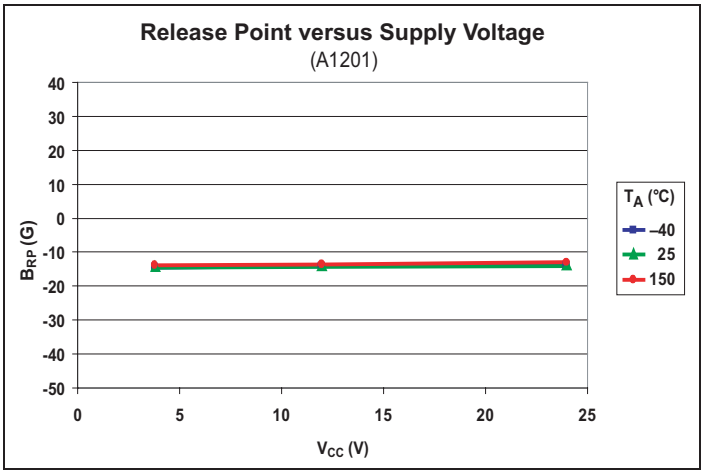
Output Voltage (On) versus Supply Voltage
(A1201/02/03/04)

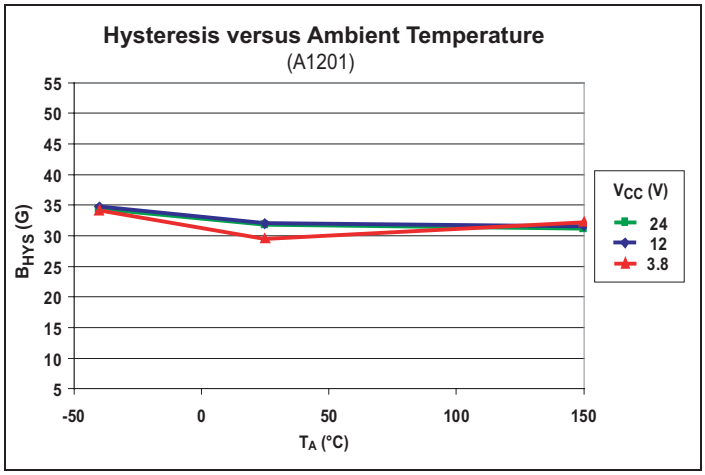


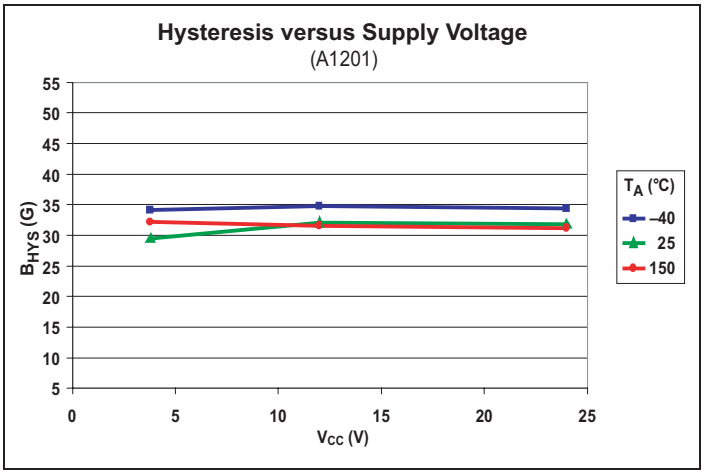

Operate Point versus Ambient Temperature
(A1201)
BOP (G)
TA (°C)
VCC (V)
24
12
3.8

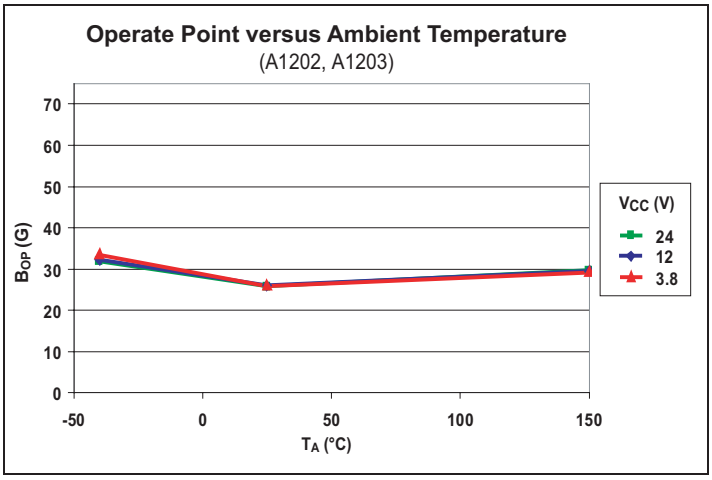

Operate Point versus Supply Voltage
(A1201)
BOP (G)
VCC (V)
TA (°C)
–40
25
150

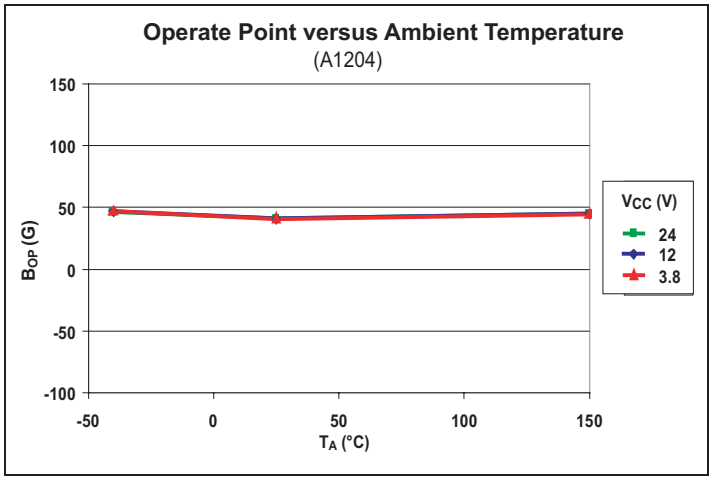

Release Point versus Ambient Temperature
(A1201)
BRP (G)
TA (°C)
VCC (V)
24
12
3.8

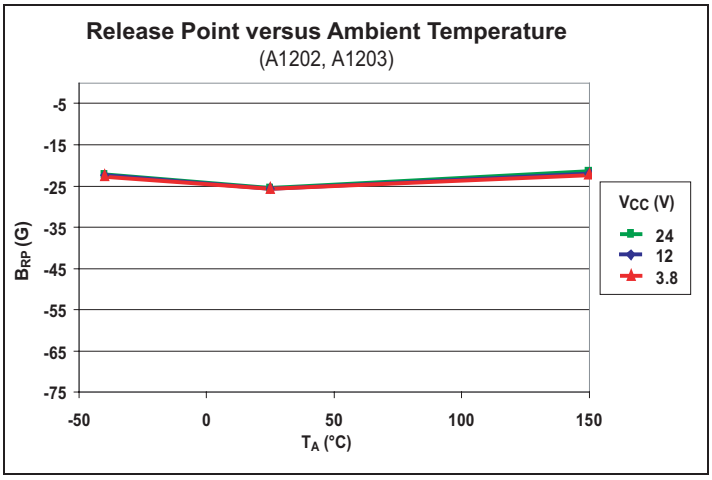

Release Point versus Supply Voltage
(A1201)
BRP (G)
VCC (V)
TA (°C)
–40
25
150

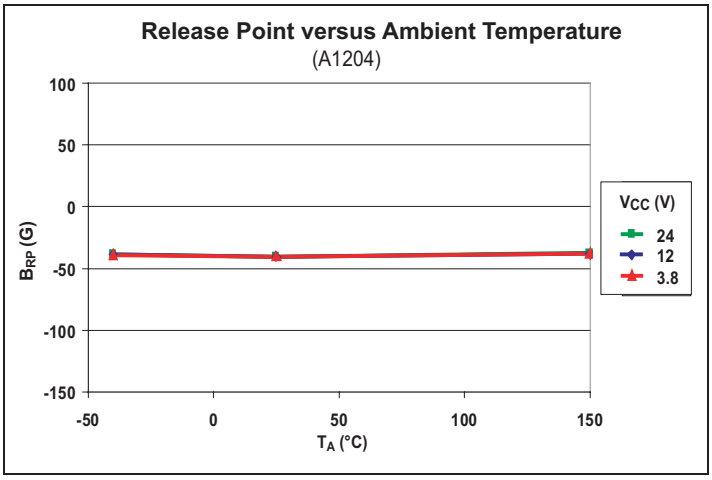

Hysteresis versus Ambient Temperature
(A1201)
BHYS (G)
TA (°C)
VCC (V)
24
12
3.8

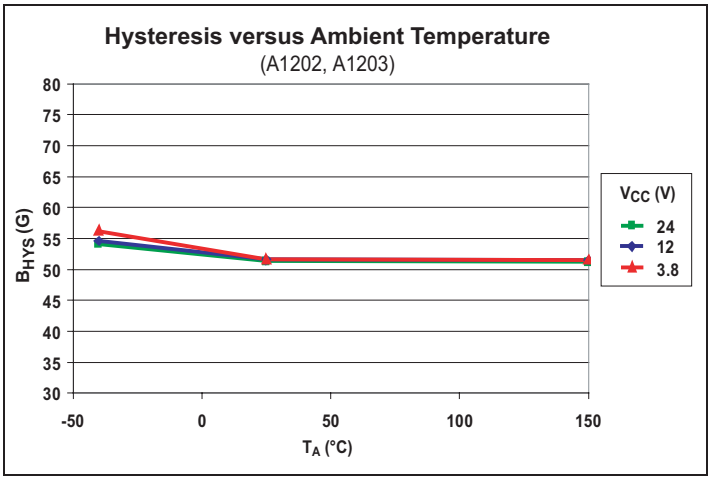

Hysteresis versus Supply Voltage
(A1201)
BHYS (G)
VCC (V)
TA (°C)
–40
25
150

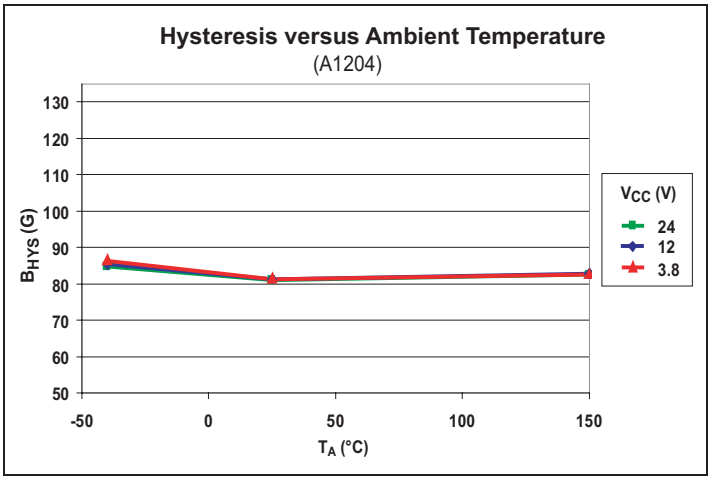

Operate Point versus Ambient Temperature
(A1202, A1203)
BOP (G)
70
60
50
40
30
20
10
0
-50
0
50
100
150
TA (°C)
VCC (V)
24
12
3.8


Operate Point versus Ambient Temperature
(A1204)
BOP (G)
150
100
50
0
-50
-100
-50
0
50
100
150
TA (°C)
VCC (V)
24
12
3.8


Release Point versus Ambient Temperature
(A1202, A1203)
BRP (G)
-5
-15
-25
-35
-45
-55
-65
-75
-50
0
50
100
150
TA (°C)
VCC (V)
24
12
3.8


Release Point versus Ambient Temperature
(A1204)
BRP (G)
100
50
0
-50
-100
-150
-50
0
50
100
150
TA (°C)
VCC (V)
24
12
3.8


Hysteresis versus Ambient Temperature
(A1202, A1203)
BHYS (G)
80
75
70
65
60
55
50
45
40
35
30
-50
0
50
100
150
TA (°C)
VCC (V)
24
12
3.8


Hysteresis versus Ambient Temperature
(A1204)
BHYS (G)
130
120
110
100
90
80
70
60
50
-50
0
50
100
150
TA (°C)
VCC (V)
24
12
3.8

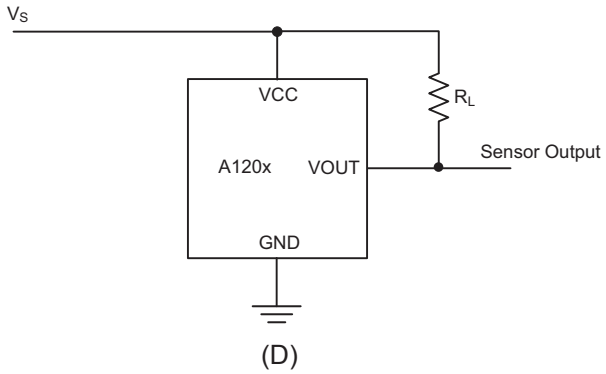
Functional Description

Bipolar Device Switching

The devices of the A120X family provide highly sensitive switching for applications using magnetic fields of alternating polarities, such as ring magnets. There are three switching modes for bipolar devices, referred to as *latch*, *unipolar switch*, and *negative switch*. Mode is determined by the switchpoint characteristics of the individual device. The characteristic hysteresis, B_{HYS}, of the device, is the difference in the relative magnetic strength and polarity of the switchpoints of the device. (Note that, in the following descriptions, a negative magnetic value indicates a north polarity field, and a positive magnetic value indicates a south polarity field. For a given value of magnetic strength, B_X, the values $-B_X$ and B_X indicate two fields of equal strength, but opposite polarity. B = 0 indicates the absence of a magnetic field.)

Bipolar devices typically behave as latches. In this mode, magnetic fields of opposite polarity and equivalent strengths are needed to switch the output. When the magnetic fields are removed $(B \rightarrow 0)$ the device remains in the same state until a magnetic field of the opposite polarity and of sufficient strength causes it to switch. The hysteresis of latch mode behavior is shown in panel A of figure 1.

In contrast to latching, when a device exhibits unipolar switching, it only responds to a south magnetic field. The field must be of sufficient strength, $> B_{OP}$, for the device to operate. When the field is reduced beyond the B_{RP} level, the device switches back to the high state, as shown in panel B of figure 1. Devices exhibiting negative switch behavior operate in a similar but opposite manner. A north polarity field of sufficient strength, $> B_{RP}$, (more north than B_{RP}) is required for operation, although the result is that V_{OUT} switches high, as shown in panel C. When



(D)

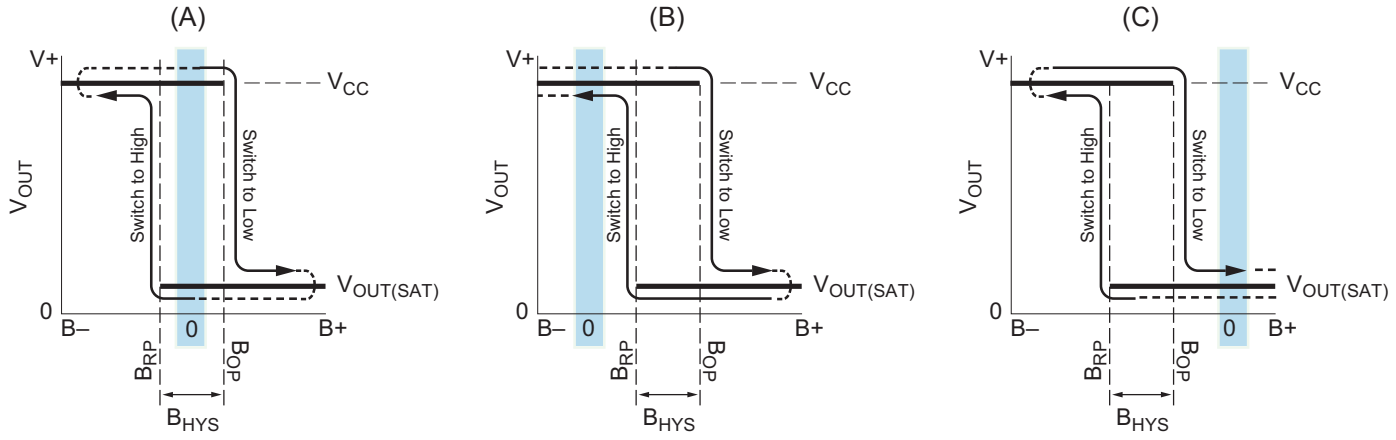


Figure 1. Bipolar Device Output Switching Modes. These behaviors can be exhibited when using a circuit such as that shown in panel D. Panel A displays the hysteresis when a device exhibits latch mode (note that the B_{HYS} band incorporates B= 0), panel B shows unipolar switch behavior (the B_{HYS} band is more positive than B = 0), and panel C shows negative switch behavior (the B_{HYS} band is more negative than B = 0). Bipolar devices, such as the 120x family, can operate in any of the three modes.

the field is reduced beyond the B_{OP} level, the device switches back to the low state.

The typical output behavior of the A120x devices is latching. That is, switching to the low state when the magnetic field at the Hall sensor exceeds the operate point threshold, B_{OP}. At this point, the output voltage is $V_{OUT(SAT)}$. When the magnetic field is reduced to below the release point threshold, B_{RP}, the device output, V_{OUT}, goes high. The values of the magnetic parameters are specified in the Magnetic Characteristics table, on page 3. Note that, as shown in figure 1, these switchpoints can lie in either north or south polarity ranges.

The A120x family is designed to attain a small hysteresis, and thereby provide more sensitive switching. Although this means that true latching behavior cannot be guaranteed in all cases, proper switching can be ensured by use of both south and north magnetic fields, as in a ring magnet. The hysteresis of the A120x family allows clean switching of the output, even in the presence of external mechanical vibration and electrical noise.

Bipolar devices adopt an indeterminate output state when powered-on in the absence of a magnetic field or in a field that lies within the hysteresis band of the device.

For more information on Bipolar switches, refer to Application Note 27705, *Understanding Bipolar Hall Effect Sensors*.

CONTINUOUS-TIME BENEFITS

Continuous-time devices, such as the A120x family, offer the fastest available power-on settling time and frequency response. Due to offsets generated during the IC packaging process, continuous-time devices typically require programming after packaging to tighten magnetic parameter distributions. In contrast, chopper-stabilized switches employ an offset cancellation technique on the chip that eliminates these offsets without the need for after-packaging programming. The tradeoff is a longer settling time and reduced frequency response as a result of the chopper-stabilization offset cancellation algorithm.

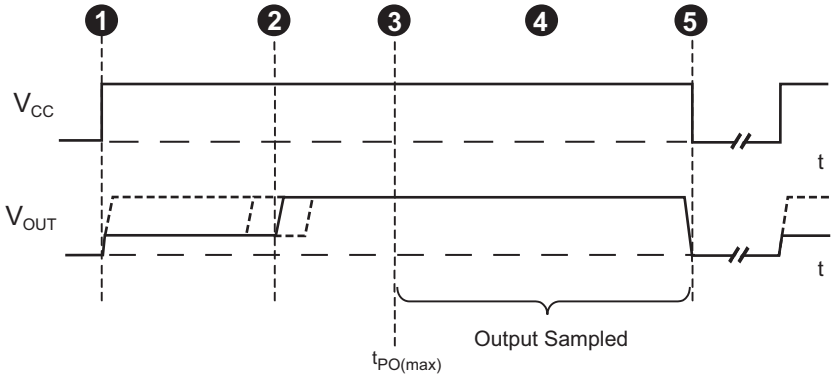


Figure 2. Continuous-Time Application, $B < B_{RP}$. This figure illustrates the use of a quick cycle for chopping V_{CC} in order to conserve battery power. Position 1, power is applied to the device. Position 2, the output assumes the correct state at a time prior to the maximum Power-On Time, $t_{PO(max)}$. The case shown is where the correct output state is HIGH. Position 3, $t_{PO(max)}$ has elapsed. The device output is valid. Position 4, after the output is valid, a control unit reads the output. Position 5, power is removed from the device.

The choice between continuous-time and chopper-stabilized designs is solely determined by the application. Battery management is an example where continuous-time is often required. In these applications, V_{CC} is chopped with a very small duty cycle in order to conserve power (refer to figure 4). The duty cycle is controlled by the power-on time, t_{PO}, of the device. Because continuous-time devices have the shorter power-on time, they are the clear choice for such applications.

For more information on the chopper stabilization technique, refer to Technical Paper STP 97-10, *Monolithic Magnetic Hall Sensor Using Dynamic Quadrature Offset Cancellation* and Technical Paper STP 99-1, *Chopper-Stabilized Amplifiers with a Track-and-Hold Signal Demodulator*.

ADDITIONAL APPLICATIONS INFORMATION

Extensive applications information for Hall-effect sensors is available in:

• *Hall-Effect IC Applications Guide*, Application Note 27701

• *Hall-Effect Devices: Gluing, Potting, Encapsulating, Lead Welding and Lead Forming*, Application Note 27703.1

• *Soldering Methods for Allegro's Products – SMT and Through-Hole*, Application Note 26009

All are provided in *Allegro Electronic Data Book*, AMS-702, and the Allegro Web site, www.allegromicro.com.

Power Derating

Power Derating

The device must be operated below the maximum junction temperature of the device, $T_{J(max)}$. Under certain combinations of peak conditions, reliable operation may require derating supplied power or improving the heat dissipation properties of the application. This section presents a procedure for correlating factors affecting operating T_J. (Thermal data is also available on the Allegro MicroSystems Web site.)

The Package Thermal Resistance, $R_{\theta JA}$, is a figure of merit summarizing the ability of the application and the device to dissipate heat from the junction (die), through all paths to the ambient air. Its primary component is the Effective Thermal Conductivity, K, of the printed circuit board, including adjacent devices and traces. Radiation from the die through the device case, $R_{\theta JC}$, is relatively small component of $R_{\theta JA}$. Ambient air temperature, T_A, and air motion are significant external factors, damped by overmolding.

The effect of varying power levels (Power Dissipation, P_D), can be estimated. The following formulas represent the fundamental relationships used to estimate T_J, at P_D.

$$P_D = V_{IN} \times I_{IN} \quad (1)$$

$$\Delta T = P_D \times R_{\theta JA} \quad (2)$$

$$T_J = T_A + \Delta T \quad (3)$$

For example, given common conditions such as: T_A= 25°C, V_{CC} = 12 V, I_{CC} = 4 mA, and $R_{\theta JA}$ = 140 °C/W, then:

$$P_D = V_{CC} \times I_{CC} = 12\ V \times 4\ mA = 48\ mW$$

$$\Delta T = P_D \times R_{\theta JA} = 48\ mW \times 140\ °C/W = 7°C$$

$$T_J = T_A + \Delta T = 25°C + 7°C = 32°C$$

A worst-case estimate, $P_{D(max)}$, represents the maximum allowable power level ($V_{CC(max)}$, $I_{CC(max)}$), without exceeding $T_{J(max)}$, at a selected $R_{\theta JA}$ and T_A.

Example: Reliability for V_{CC} at T_A = 150°C, package UA, using minimum-K PCB.

Observe the worst-case ratings for the device, specifically: $R_{\theta JA}$ = 165°C/W, $T_{J(max)}$ = 165°C, $V_{CC(max)}$ = 24 V, and $I_{CC(max)}$ = 7.5 mA.

Calculate the maximum allowable power level, $P_{D(max)}$. First, invert equation 3:

$$\Delta T_{max} = T_{J(max)} - T_A = 165\,°C - 150\,°C = 15\,°C$$

This provides the allowable increase to T_J resulting from internal power dissipation. Then, invert equation 2:

$$P_{D(max)} = \Delta T_{max} \div R_{\theta JA} = 15°C \div 165\ °C/W = 91\ mW$$

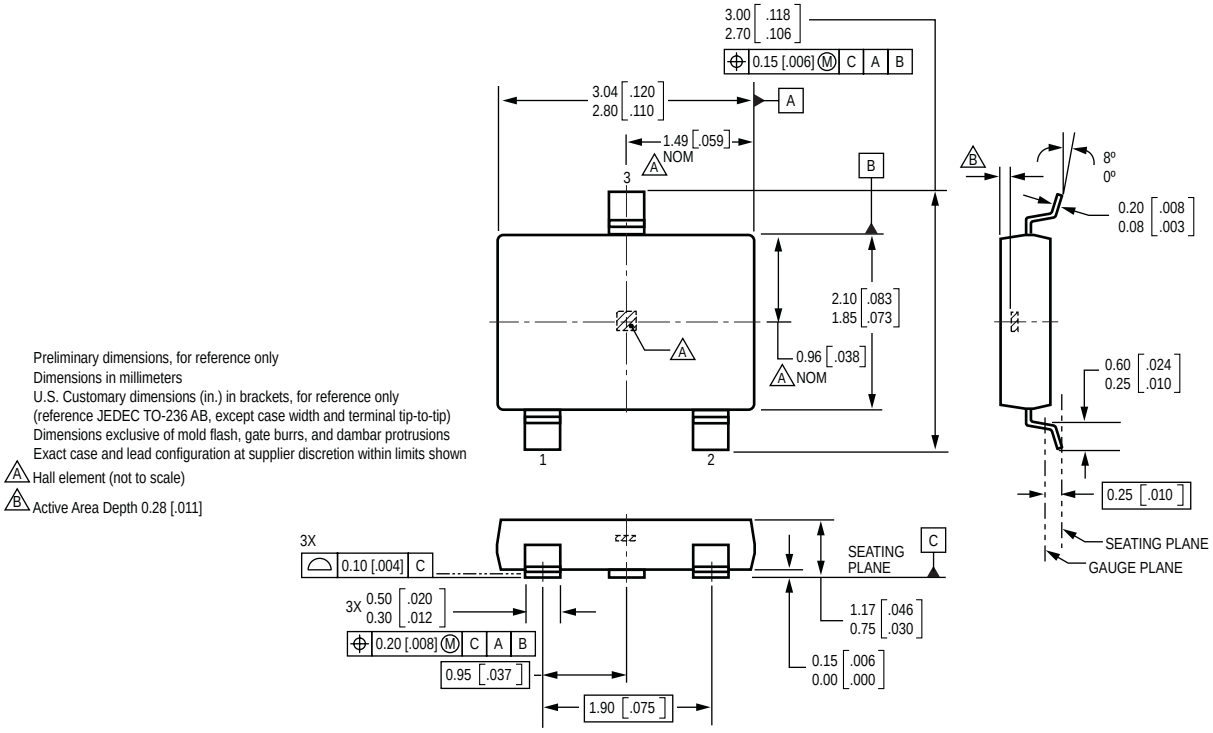
Finally, invert equation 1 with respect to voltage:

$$V_{CC(est)} = P_{D(max)} \div I_{CC(max)} = 91\ mW \div 7.5\ mA = 12.1\ V$$

The result indicates that, at T_A, the application and device can dissipate adequate amounts of heat at voltages $\leq V_{CC(est)}$.

Compare $V_{CC(est)}$ to $V_{CC(max)}$. If $V_{CC(est)} \leq V_{CC(max)}$, then reliable operation between $V_{CC(est)}$ and $V_{CC(max)}$ requires enhanced $R_{\theta JA}$. If $V_{CC(est)} \geq V_{CC(max)}$, then operation between $V_{CC(est)}$ and $V_{CC(max)}$ is reliable under these conditions.

Package LH, 3-Pin (SOT-23W)



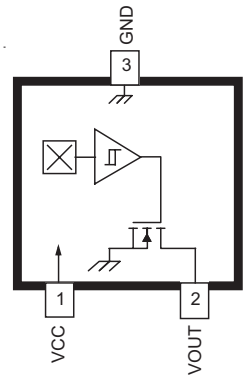
Preliminary dimensions, for reference only
Dimensions in millimeters
U.S. Customary dimensions (in.) in brackets, for reference only
(reference JEDEC TO-236 AB, except case width and terminal tip-to-tip)
Dimensions exclusive of mold flash, gate burrs, and dambar protrusions
Exact case and lead configuration at supplier discretion within limits shown

A Hall element (not to scale)

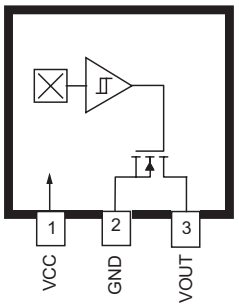
B Active Area Depth 0.28 [.011]

Pin-out Diagrams

Package LH



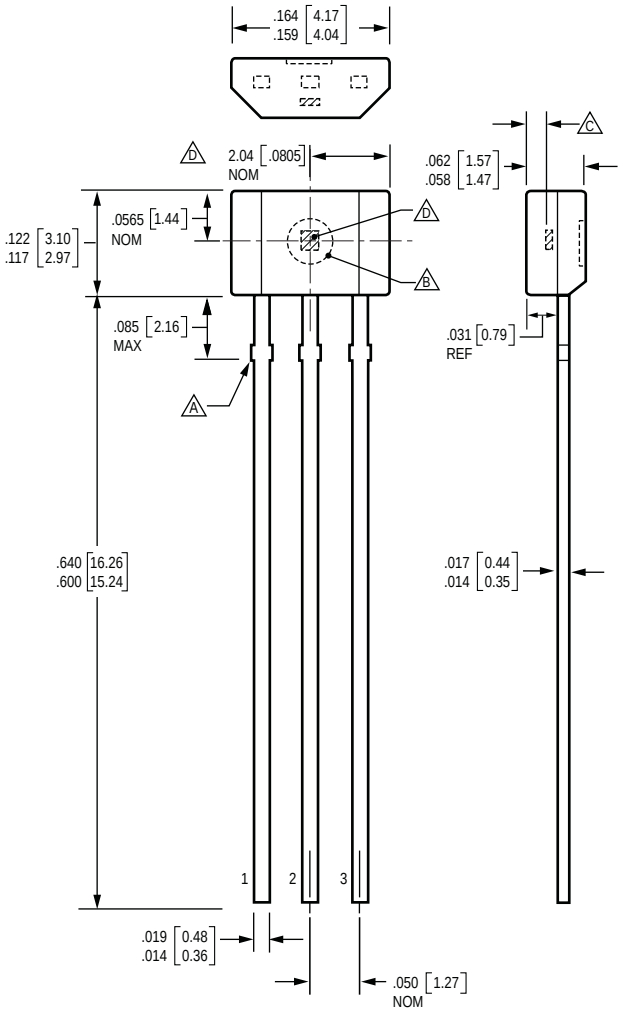
Package UA



Terminal List

Name	Description	Number	
		Package LH	Package UA
VCC	Connects power supply to chip	1	1
VOUT	Output from circuit	2	3
GND	Ground	3	2

Package UA, 3-Pin SIP



Dimensions in inches
Metric dimensions (mm) in brackets, for reference only

A Dambar removal protrusion (6X)
B Ejector mark on opposite side
C Active Area Depth .0195 [0.50] NOM
D Hall element (not to scale)

The products described herein are manufactured under one or more of the following U.S. patents: 5,045,920; 5,264,783; 5,442,283; 5,389,889; 5,581,179; 5,517,112; 5,619,137; 5,621,319; 5,650,719; 5,686,894; 5,694,038; 5,729,130; 5,917,320; and other patents pending.
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